Vishay Semiconductors

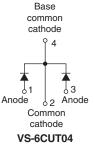
High Performance Schottky Generation 5.0, 2 x 3 A

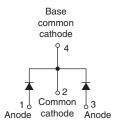




I-PAK (TO-251AA)

D-PAK (TO-252AA)





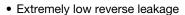
JT04 VS-6CWT04FN

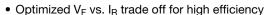
PRODUCT SUMMARY					
Package	D-PAK (TO-252AA), I-PAK (TO-251AA)				
I _{F(AV)}	2 x 3 A				
V_{R}	45 V				
V _F at I _F	0.54 V				
I _{RM} max.	3 mA at 125 °C				
T _J max.	175 °C				
Diode variation	Common cathode				
E _{AS}	14 mJ				

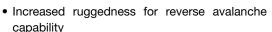
FEATURES











- RBSOA available
- Negligible switching losses
- Submicron trench technology
- Compliant to RoHS Directive 2002/95/EC

APPLICATIONS

- Specific for PV cells pybass diode
- High efficiency SMPS
- High frequency switching
- Output rectification
- Reverse battery protection
- Freewheeling
- DC/DC systems
- Increased power density systems

MAJOR RATINGS AND CHARACTERISTICS							
SYMBOL	CHARACTERISTICS VALUES UNITS						
V _{RRM}		45	V				
V _F	3 Apk, T _J = 125 °C (typical, per leg)	0.46	V				
T _J	Range	- 55 to 175	°C				

VOLTAGE RATINGS				
PARAMETER	SYMBOL	TEST CONDITIONS	VS-6CUT04 VS-6CWT04FN	UNITS
Maximum DC reverse voltage	V_{R}	T _J = 25 °C	45	V

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ABSOLUTE MAXIMUM RATINGS								
PARAMETER		SYMBOL	TEST CONDITIONS		VALUES	UNITS		
Maximum average	per leg		50 % duty cycle at T _C = 166 °C, rectangular waveform		FO 0/ duty evals at T 166 °C vector gular vector		3	А
forward current	per device	I _{F(AV)}			6	A		
Maximum peak one c	cycle	l	5 μs sine or 3 μs rect. pulse Following any rated load condition and with rated V _{RRM} applied		440	А		
non-repetitive surge o	current per leg	IFSM			70	^		
Non-repetitive avalanche energy per leg		E _{AS}	T _J = 25 °C, I _{AS} = 1.3 A, L = 16 mH		14	mJ		
Repetitive avalanche	current per leg	I _{AR}	Limited by frequency of operation and time pulse duration so that $T_J < T_J max$. I_{AS} at $T_J max$. as a function of time pulse (see fig. 8)		I _{AS} at T _J max.	А		

ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS		TYP.	MAX.	UNITS
Forward voltage drop per leg	V _{FM} ⁽¹⁾	3 A	T _J = 25 °C	0.535	0.600	V
		6 A		0.615	0.680	
		3 A	T _J = 125 °C	0.485	0.540	
		6 A		0.570	0.640	
Reverse leakage current per leg	I _{RM} ⁽¹⁾	T _J = 25 °C	V _R = Rated V _R	-	25	μΑ
		T _J = 125 °C		-	3	mA
Junction capacitance per leg	C _T	$V_R = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz), 25 °C		240	-	pF
Series inductance per leg	L _S	Measured lead to lead 5 mm from package body		8.0	-	nH
Maximum voltage rate of change	dV/dt	Rated V _R		-	10 000	V/µs

Note

 $^{^{(1)}\,}$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	SYMBOL TEST CONDITIONS		UNITS	
Maximum junction and storage temperature range	T_J , T_{Stg}		- 55 to 175	°C	
Maximum thermal resistance, junction to case per leg	В	DC operation	4.7		
Maximum thermal resistance, junction to case per device	R _{thJC}		2.35	°C/W	
Typical thermal resistance, case to heatsink	R _{thCS}		0.3		
Approximate weight			0.3	g	
			0.01	OZ.	
Madra da ta		Case style I-PAK		6CUT04	
Marking device		Case style D-PAK	6CWT	04FN	

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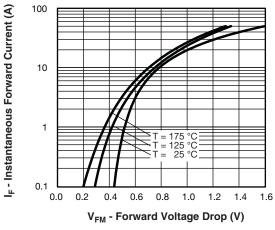


Fig. 1 - Maximum Forward Voltage Drop Characteristics

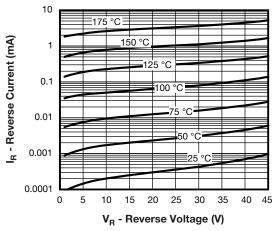


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

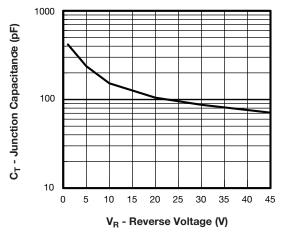


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

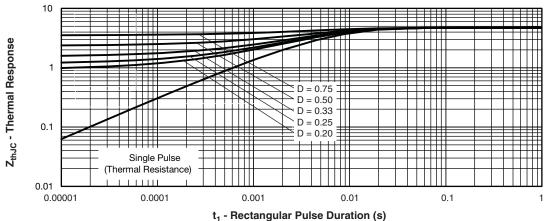


Fig. 4 - Maximum Thermal Impedance Z_{th-IC} Characteristics

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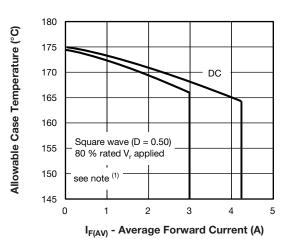


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

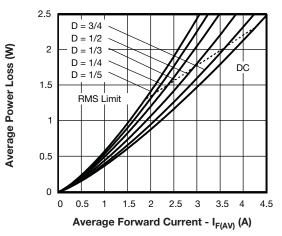


Fig. 6 - Forward Power Loss Characteristics

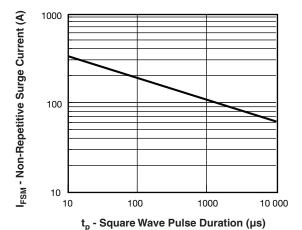


Fig. 7 - Maximum Non-Repetitive Surge Current

Note

 $^{(1)}$ Formula used: T_C = T_J - (Pd + Pd_{REV}) x R_{th,JC}; Pd = Forward power loss = I_{F(AV)} x V_{FM} at (I_{F(AV)}/D) (see fig. 6); Pd_{REV} = Inverse power loss = V_{R1} x I_R (1 - D); I_R at V_{R1} = 80 % rated V_R

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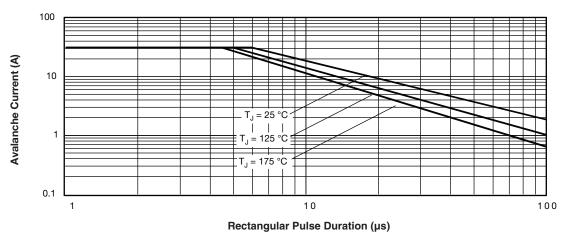


Fig. 8 - Reverse Bias Safe Operating Area (Avalanche Current vs. Rectangular Pulse Duration)

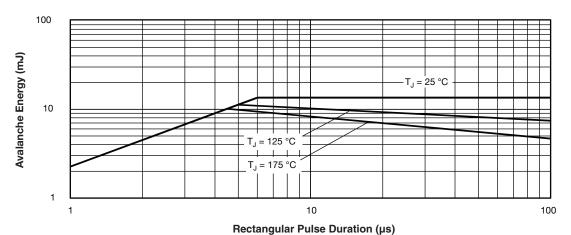
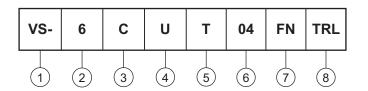


Fig. 9 - Reverse Bias Safe Operating Area (Avalanche Energy vs. Rectangular Pulse Duration)

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ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Current rating (6 A)

- Circuit configuration:

C = Common cathode

4 - Package:

• U = I-PAK

 \bullet W = D-PAK

5 - T = Trench

6 - Voltage rating (04 = 45 V)

7 - TO-252AA (D-PAK)

8 - D-PAK, I-PAK:

None = Tube (75 pieces)

D-PAK only:

• TR = Tape and reel

• TRL = Tape and reel (left oriented)

• TRR = Tape and reel (right oriented)

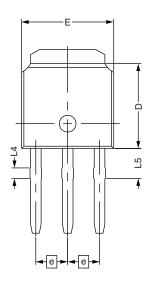
LINKS TO RELATED DOCUMENTS					
Dimensions	I-PAK (TO-251AA)	www.vishay.com/doc?95024			
Dimensions	D-PAK (TO-252AA)	www.vishay.com/doc?95448			
Part marking information	I-PAK (TO-251AA)	www.vishay.com/doc?95025			
	D-PAK (TO-252AA)	www.vishay.com/doc?95059			
Packaging information		www.vishay.com/doc?95033			
SPICE model		www.vishay.com/doc?95038			

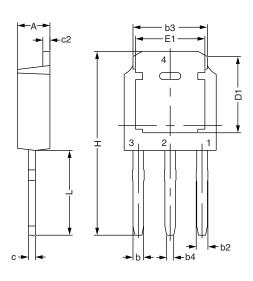


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I-PAK - S

DIMENSIONS FOR I-PAK - S in millimeters





SYMBOL	DIMENSIONAL REQUIREMENTS				
STWIBOL	MIN.	NOM.	MAX.		
E	6.40	6.60	6.70		
L	3.98	4.13	4.28		
L4	0.66	0.76	0.86		
L5	1.96	2.16	2.36		
D	6.00	6.10	6.20		
Н	11.05	11.25	11.45		
b	0.64	0.76	0.88		
b2	0.77	0.84	1.14		
b3	5.21	5.34	5.46		
b4	0.41	0.51	0.61		
е		2.286 BSC			
Α	2.20	2.30	2.38		
С	0.40 0.50		0.60		
c2	0.40	0.40 0.50 0.6			
D1	5.30		-		
E1	4.40	-	-		



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Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.

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Revision: 02-Oct-12 Document Number: 91000